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# ANALYSIS OF SPEED POWER PERFORMANCE OF SINGLE BIT HIGH SPEED ADDER 

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#### Abstract

The essential problems within the progression of terribly monumental size of reconciliation circuit configuration is that the evaluate of temporal arrangement conducts of the quantity juggling circuits. The idea of smart effort offers a capable thanks to affect fathom and survey the temporal order conduct of circuits with regular CMOS (C-CMOS) structure. Nonetheless, this method isn't operating for circuits with a cross breed structure. Then again, numerous circuits with the cross breed structure that are faster and expend less force than C-CMOS one are projected for various applications maybe, convenient and IoT gadgets. Right now, would like of getting and utilization of a basic and skilful coming up with conduct strategy like regular wise travail for examination of the 0.5 breed snake circuits is inescapable. This journal proposes a productive examination conjointly, displaying methodology that empowers architects to gauge the temporal order conduct of half and half full snake circuits at the square level additionally, envision their presentation in period of time circuits. The addition conjointly, determination issue are conferred as a basis for precise determination and improvement the 0.5 and half snake cells quantitative on the only check seat for the board of vitality proficiency and execution trade off. The projected technique is researched utilizing 22 NM CMOS Technique.


## I. INTRODUCTION

Snake Circuits are the most fundamental square of any advanced framework. In any number- crunching capacity expansion assumes a job of most essential activity. Adders are usually utilized in incidental application in present day VLSI framework like multiplier configuration, structure of an ALU, and furthermore in different Digital Signal Processing calculations like FIR, IIR Filter plan. Structuring an incredible and proficient of a snake circuit a creator must enhance the parameters like zone, postponement, and force. We need to trade off between every one of the three parameters to get a productive plan. Contingent on the need and application a few changes and bargains must be made. In present day VLSI plan time delay in information way considered as a vital parameter nowadays. Creators deferral as the accelerate activity turns out to be quicker There has been parcel of explores and work with respect to limiting of postponement and now planner search for making a viper circuit which is productive and altogether quicker.

A full ophidian is structured utilizing a couple of explanation designs, wherever every vogue has its favorable circumstances and impediments. The foremost renowned explanation vogue in monumental size of combination circuit configuration is ancient CMOS (C-CMOS) that has pull-up what's additional, pull-down electronic transistor systems.

The draw up compose is in light-weight of plan and equivalent pMOS transistors, and pull-down sort out relies upon game plan and equivalent nMOS transistors. The C-CMOS vogue full snake is that the general CMOS structure with standard draw up and pull-down frameworks giving decent drive abilities and full yield swing. On the contrary hand-CMOS circuits cause all the extra short out blessing and that is basically the beginning powerful current at trading time, that causes extra power use in connection with blend clarification ones. When in doubt, 0.5 and half structure circuits have less relationship with the power offer and ground in connection with C-CMOS circuits. Also, C-CMOS full snake has a huge information capacitance by virtue of the quantity of relationship with the pMOS and nMOS semiconductor gadget that reduces the speed. 0.5 variety clarification vogue utilizes the characteristics of express method of reasoning plans for their execution to redesign the introduction of the set up it's famous that the first acknowledged circuits cautious inside the crossbreed structure are full adders because the unpredictability of attempt to confine the circuit turns into all the a ton of definitely with expanding the square size and in this manner the measure of information sources and yields, as an example, blowers, pass on save adders, and so forth inside the entryway level, regularly prestigious circuits with blend
structure are two-and three-input XOR and XNOR circuits that they're the center of full adders furthermore. Subsequently, full snake hinders with varied information yield drive conditions are thought-about right away. Notwithstanding varied points of interest that are accounted for a few crossover full adders like region power-vitality effectiveness, commotion tolerant, and fast, the basic issue in their usage is anomaly moreover, varied nature of their structure. Right now, cell arrange philosophy (CDM) and precise CDM these techniques are displayed in order that they will keep their preferences with focus on key functions of the circuit structure. These key focuses are a base variety of transistors on the essential manner, halfing the circuit to explanation part and drive part, the weak and baseless structure of the explanation half, the employment of varied correct instruments for various attributes, etc

To have the cream standard style, as a solid principle style like C-CMOS, ace electronic transistor measure estimation is another issue. This referenced measure technique should be adjustable for covering varied nature of the circuits with half breed structure in lightweight of the evident reality that the standard levelheaded effort wasn't working for them. to Illustrate, inside the standard smart travail, the comparable semiconductor devices will get the comparative size seeable of transistor unit size, and for the strategy transistors, the size of each semiconductor contraption depends on the proportion of transistors on the approach drive and transistor unit size. For the circuits with a half and half structure, this strategy isn't working, in lightweight of the very fact that the circuit structure is dynamically wooly-objected.

Direct mindful calculation (DMC) has been foreseen as a heuristic procedure for movement and evaluating of the circuits with cream structure. this is much of the time advantageous estimation tally, that is adaptable for covering all of structure involution and associating with attributes of the circuit in single- object and multi object upgrades, in any case this approach doesn't work for delay evaluate or transient solicitation lead assessment. The possibility of veritable effort was beginning shown by Sutherland et al. The report undeniably reveals the best approach to manage display the C-CMOS circuits for each circuit progress with estimation and suspension appearing of single-stage and time span structures. All the starting late dealt with works focused on the insightful effort of C-CMOS explanation style circuits as an outcomes of their mounted and veritable structure. Be that since it could, for cream rule circuits, another framework is required to frustrate down the circuit lead because of their dazed structure Another most mainstream circumstance of this diary is to shape clear thoughts on the best appreciation to pick and use snake hinders with half and half structure. For example, a tiny bit of the complete adders are low force or significance fruitful after they are parting unendingly at one explore seat with express information yield drive conditions. Be that since it might, they're not working sensibly inside the time period structures by prudence of the nonattendance of drivability and their monstrous information capacitance. With adding a cushion to reimburse their nonappearance of drive. They can work suitably, in any case they couldn't be accomplice degree gainful cell in light-weight of the very fact that the whole circuit has some overhead of zone, force, and centrality use with further support. This diary is fruitful for significantly understanding the snake circuits with a mix structure to guarantee they might be reliable squares in time span structures at the same time they're the best for the goal parameters, for instance, force, centrality, etc.

This journal has the potential for rising the mechanical gadgets for timing assessment as well. The focal issue immediately what are the major parameters that architect must think about for the circuits with 0.5 and half structure inside the single check seat, for extraction of a total planning behavior of the snake cells? Without a moment's delay, new methodology is wanted to inquire about the look lead of the 0.5 and half full adders with the segregated structure, additionally, straightforwardness is considered generally speaking the arranged system.

The intersection transistor work full snake (TFA), transmission entranceway full snake (TGA), New- HPSC, TPA as most idea 0.5 variety full adders with various information yield drive conditions are picked in connection with the C-CMOS full snake for running this new procedure.

(a)

(b)

(c)

Fig 1 (a) TGA with input drive ways (b) C-CMOS (c) TFA (d) New -HPSC

## II. POWER CONSIDERATIONS

Arranging systems having some expertise in low power is not the slightest bit a quick task, since it is locked in with all the IC design stages starting with the structure direct delineation and fruition with the creation and packaging structures. in an exceedingly bit of those stages there are decides that are clear and there are steps to

Follow that lessen power use, possibly, diminishing the power offer voltage.
There are 3 fundamental sections of force scattering in correlative metal-oxide-semiconductor (CMOS) circuits.

1) Shift Power: Power eaten by the circuit center capacitances all through semiconductor gadget trading.
2) Short Power: Power gobbled up gratitude to the current spilling out of force offer to ground all through electronic transistor trading
3) Static Power: due to spillage and static streams.

Dynamic power sets up the greater part of the power disseminated in CMOS VLSI circuits. it's the power appropriated all through charging or passionate the pile capacitance of a given Circuit. It relies on the information style which will either construct the transistors switch or to not switch at each clock cycle.

Assessing the power of a colossal circuit might be an interesting assignment. Heuristic counts, quantifiable, and probabilistic methods are used to give supreme information guides to check the trading activity of the circuit. These ways calmed down exact once the size of the circuit increases. it's more brilliant to hinder down the huge circuit into tinier modules and thereafter use these approaches to assess the power use of every module. At the reason once the spoiled modules are adequately little, cautious strategies are used to support their display. pc engine helped style mechanical assemblies and investigate frameworks may be utilized to develop the circuit design, recreate it, and measure its capacity scattering. Following this procedure, the best set up of a given module is found and later by partner the modules along the greater circuit is surrounded, which can be redesigned for low-power spread.

## III. FULL ADDER BUILDING BLOCK

The full-adder operate may be represented as follows: Given the 3 1-bit inputs, , and , it's desired to calculate the 21 -bit outputs total and Cout.

# sum $=(A \oplus B) \oplus C_{\text {in }}$ <br> $$
C_{\mathrm{out}}=A \cdot B+C_{\mathrm{in}} \cdot(A \oplus B)
$$ 

There are customary implementations for the full-adder cell that may be used as basis for comparison during this journal. Among these adders there are the following::

1) TGA (Transmission Gate Full Adder) with inputs drive path. With fourteen electronic transistor technology.
2) As most well liked hybrid full adders with totally different input-output drive conditions are designated as compared with the C-CMOS full adder for running this new technique.
3) The transmission operate full-adder (TFA) cell is predicated on the transmission function theory and it's sixteen transistors.
4) New-HPSC model carries with it NOR/XNOR design of wholly consisting of 26 transistors.

## A. Shift Time

The exchanging time of the circuits is calculable at a solitary check seat, once yield is related to the support at two specific info yield conditions. These two things are unit drivability state of the past stage and also the unit yield electrical device. The exchanging time is engendering delay at the quality data yield drive condition and basic parameter however not adequate parameter to understand the design conduct of the total snake in period of time structures. Consequently, the drive ability and information capacitance are thought-about as basic parameters aboard exchanging time that structure an essential piece of our coming up with conduct examination

## B. Drive Capability

Circuit drivability is that the capability of the yield of the circuit to drive the particular burden suitably. Lesser time the circuit takes to charge the yield condenser, more and more clear is that the drive ability of the circuit. For this investigation, the yield is within the evaluate of the complete snake execution in time period structure because the issue chooses however fast a selected cell goes to charge the data capacitance of the subsequent stage sort of a gift supply and may demonstrate each RC of the cell additionally to C-Load.

## C. Input Capacitance

Data capacitance is an important parameter for temporal order assessment and may be composed with "g" within the commonplace sound effort. The take a look at seat used is that the electrical converter driving each commitment of the complete snake with the moving weight capacitors connected with the overall and pass away terminals. The delay offered by the commitment of the total snake to the driving electrical converter is resolved, and also the physical evaluate of the capacitance that causes a comparable deferral is confirmed because the info capacitance.

The biggest evaluate of the \{information\} capacitances is taken into account as information capacitance of the total snake.

(a) Single Test Bench

Fig 2 (a) Single test bench used for simulation

## IV. SIMULATION AND RESULTS ANALYSIS

A) Experimental Setup

Right now, is employed as circuit take a look at system for all reenactments; 22-nm MOS discerning innovation model (PTM) model and 22 nm Metal Gate/High-K/Strained-Si PTM model are thought of as two distinctive advances for examination. For single-arrange examination, each full snake are recreated on a solitary take a look at seat appeared in Fig. 2(a). This single take a look at seat incorporates data and yield cushions. every of the 86 potential advances are applied for the postponement and force evaluate. The ascent time and falls time of the knowledge beats are viewed as 10 PS and force provide has been viewed as 0.8 V .
TABLE - I

TRANSIENT ANALYSIS OF ADDER WITH DIFFERENT TEMPERATURE

| $\begin{aligned} & \text { Temp= } \\ & 20.000 \end{aligned}$ | $\begin{aligned} & \mathrm{tpd}= \\ & 3.1344 \mathrm{E}-11 \end{aligned}$ | $\begin{aligned} & \hline \text { s_delay=- } \\ & 4.8836 \mathrm{E}-11 \end{aligned}$ | $\begin{aligned} & \text { s_power= } \\ & 4.3664 \mathrm{E}-05 \end{aligned}$ |
| :---: | :---: | :---: | :---: |
| $\begin{aligned} & \text { Temp= } \\ & 30.000 \end{aligned}$ | $\begin{aligned} & \text { tpd }= \\ & 3.1432 \mathrm{E}-11 \end{aligned}$ | $\begin{aligned} & \hline \text { s_delay }=- \\ & 5.0359 \mathrm{E}-11 \end{aligned}$ | $\begin{aligned} & \text { s_power= } \\ & 3.8423 \mathrm{E}-05 \end{aligned}$ |
| $\begin{aligned} & \hline \text { Temp= } \\ & 40.000 \end{aligned}$ | $\begin{aligned} & \text { tpd }= \\ & 3.2390 \mathrm{E}-11 \end{aligned}$ | $\begin{aligned} & \hline \text { s_delay }=- \\ & 5.2948 \mathrm{E}-11 \end{aligned}$ | $\begin{aligned} & \text { s_power= } \\ & 3.3845 \mathrm{E}-05 \end{aligned}$ |
| $\begin{gathered} \text { Temp= } \\ 50.000 \end{gathered}$ | $\begin{aligned} & \text { tpd }= \\ & 3.3708 \mathrm{E}-11 \end{aligned}$ | $\begin{aligned} & \hline \text { s_delay }=- \\ & 5.5457 \mathrm{E}-11 \end{aligned}$ | $\begin{aligned} & \text { s_power= } \\ & 2.9728 \mathrm{E}-05 \end{aligned}$ |
| $\begin{aligned} & \text { Temp= } \\ & 60.000 \end{aligned}$ | $\begin{aligned} & \text { tpd }= \\ & 3.4909 \mathrm{E}-11 \end{aligned}$ | $\begin{aligned} & \hline \text { s_delay }=- \\ & 5.6811 \mathrm{E}-11 \end{aligned}$ | $\begin{aligned} & \text { s_power= } \\ & 2.6189 \mathrm{E}-05 \end{aligned}$ |
| $\begin{aligned} & \text { Temp= } \\ & 70.000 \end{aligned}$ | $\begin{aligned} & \text { tpd }= \\ & 3.5879 \mathrm{E}-11 \end{aligned}$ | $\begin{aligned} & \hline \text { s_delay }=- \\ & 5.8292 \mathrm{E}-11 \end{aligned}$ | $\begin{aligned} & \text { s_power= } \\ & 2.2996 \mathrm{E}-05 \end{aligned}$ |
| $\begin{aligned} & \text { Temp= } \\ & 80.000 \end{aligned}$ | $\begin{aligned} & \text { tpd }= \\ & 3.7201 \mathrm{E}-11 \end{aligned}$ | $\begin{aligned} & \hline \text { s_delay=- } \\ & 5.9778 \mathrm{E}-1 \end{aligned}$ | $\begin{aligned} & \text { s_power= } \\ & 2.0326 \mathrm{E}-05 \end{aligned}$ |
| $\begin{aligned} & \text { Temp= } \\ & 90.000 \end{aligned}$ | $\begin{aligned} & \text { tpd= } \\ & 3.8648 \mathrm{E}-11 \end{aligned}$ | $\begin{aligned} & \hline \text { s_delay=- } \\ & 6.1251 \mathrm{E}-11 \end{aligned}$ | $\begin{aligned} & \text { s_power= } \\ & 1.7955 \mathrm{E}-05 \end{aligned}$ |
| $\begin{aligned} & \text { Temp }= \\ & 100.000 \end{aligned}$ | $\begin{aligned} & \mathrm{tpd}= \\ & 4.0075 \mathrm{E}-11 \end{aligned}$ | $\begin{aligned} & \hline \text { s_delay }=- \\ & 6.2706 \mathrm{E}-11 \end{aligned}$ | $\begin{aligned} & \text { s_power= } \\ & 1.5941 \mathrm{E}-05 \end{aligned}$ |


(a)

(b)

(c)

(d)

(e)

(i)

(j)

(k)

Fig 4. Period Analysis of Full Adders (a) Voltages A, B, Cin, Sum and Cout (b) Currents I (Vdd Sources) (c) Tpd (d) S_delay (e) S_power (f) Temperature (g) Overall Currents I (V1,V2 and V3) (h) Tpowrd Power in C-CMOS (i) Input Voltages A, B, Cin of C- CMOS (j) Sum output of C-CMOS (k) Cout of C-CMOS.

## V. CONCLUSION

At this moment, new shrewd exertion assessment is arranged forward hybrid structure snake circuits. The focal issue immediately, we tend to are noticing is, if hybrid full adders are quick, essentialness domain great over C-CMOS one, what are the parameters that organizer will examine and the board to affirm they're reliable squares to use inside the timeframe structure in an exceedingly fundamental system like standard steady exertion. This assessment is fundamental to pass judgment on the introduction of the all out Adders in greater structures, for instance, mammoth adders, blowers, multipliers, and so forth. In lightweight of the ramifications of entertainment at the one check seat and assessment with timeframe examination for the recorded full adders, at this moment, fleeting plan lead are regularly incontestable using: trading time, input capacitance, and yield drivability. of these 3 things are quantitative by usage of the one check seat, and with these 3 things, it's possible to foresee worldly course of action lead of the circuit for timeframe Structures.

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